

1A, 200V - 1000V Surface Mount Rectifier

FEATURES

- · Glass passivated junction chip
- Ideal for automated placement
- Low profile package
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- High frequency rectification
- Freewheeling application
- Switching mode converters and inverters in computer, automotive and telecommunication

MECHANICAL DATA

- Case: SOD-128
- Molding compound meets UL 94V-0 flammability rating
- Part no. with suffix "H" means AEC-Q101 qualified
- Packing code with suffix "G" means green compound (halogen-free)
- Moisture sensitivity level: level 1, per J-STD-020
- Terminal: Mattle tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.027 g (approximately)

KEY PARAMETERS					
PARAMETER	VALUE	UNIT			
I _{F(AV)}	1	Α			
V_{RRM}	200 - 1000	V			
I _{FSM}	30	Α			
T_{JMAX}	150	°C			
Package	SOD-128				
Configuration	Single die				





SOD-128

PARAMETER	SYMBOL	S1DFS	S1GFS	S1JFS	S1KFS	S1MFS	UNIT
Marking code on the device		S1DFS	S1GFS	S1JFS	S1KFS	S1MFS	
Repetitive peak reverse voltage	V_{RRM}	200	400	600	800	1000	V
Reverse voltage, total rms value	V _{R(RMS)}	140	280	420	560	700	V
Forward current	I _{F(AV)}			1			Α
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}			30			А
Junction temperature	TJ	- 55 to +150		°C			
Storage temperature	T _{STG}	T _{STG} - 55 to +150		°C			

1



THERMAL PERFORMANCE					
PARAMETER	SYMBOL	TYP	UNIT		
Junction-to-lead thermal resistance per diode	$R_{\Theta JL}$	29	°C/W		
Junction-to-ambient thermal resistance per diode	$R_{\Theta JA}$	82	°C/W		
Junction-to-case thermal resistance per diode	R _{eJC}	30	°C/W		

Thermal Performance Note: Units mounted on recommended PCB (5mm x 5mm Cu pad test board)

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS SYMBOL		TYP	MAX	UNIT	
	$I_F = 0.5A, T_J = 25^{\circ}C$	V _F	0.91	1.0	V	
Forward voltage per diode (1)	$I_F = 1.0A, T_J = 25^{\circ}C$		0.99	1.1	V	
	I _F = 0.5A, T _J = 125°C		0.78	0.87	V	
	I _F = 1.0A, T _J = 125°C		0.85	0.95	V	
Daviers augment @ reted V nor diede (2)	T _J = 25°C		-	1	μΑ	
Reverse current @ rated V _R per diode ⁽²⁾	T _J = 125°C	l _R	-	50	μΑ	
Junction capacitance	1 MHz, V _R =4.0V	CJ	9	-	pF	

Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms

ORDERING INFORMATION					
PART NO.	PART NO. SUFFIX(*)	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING
S1xFS	Н	MW	G	SOD-128	3,500 / 7" Plastic reel
(Note 1, 2)	"	MX	G	SOD-128	14,000 / 13" Plastic reel

Notes:

- 1. "xx" defines voltage from 200V (S1DFS) to 1000V (S1MFS)
- 2. Whole series with green compound (halogen-free)
- *: Optional available

EXAMPLE P/N					
EXAMPLE P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
S1DFSHMWG	S1DFS	Н	MW	G	AEC-Q101 qualified Green compound



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.1 Forward Current Derating Curve

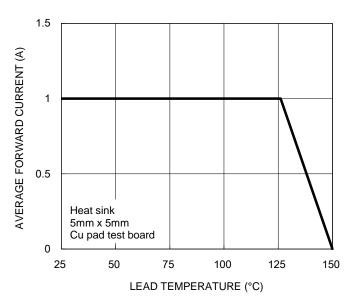


Fig.2 Typical Junction Capacitance

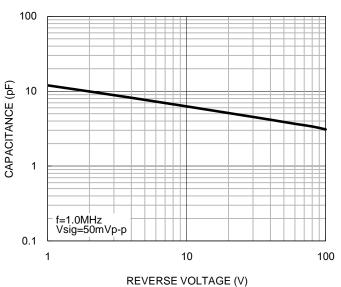


Fig.3 Typical Reverse Characteristics

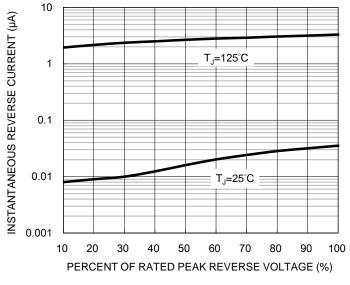
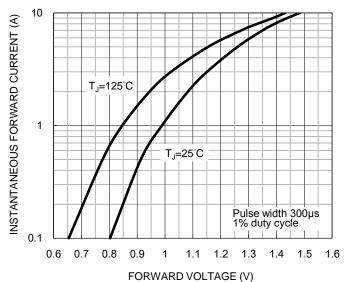


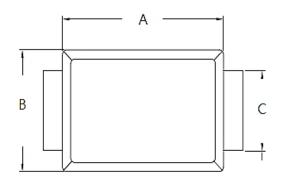
Fig.4 Typical Forward Characteristics

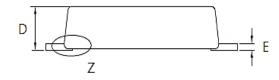


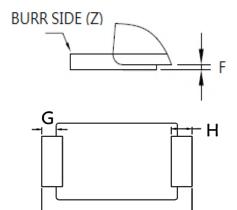


PACKAGE OUTLINE DIMENSIONS

SOD-128



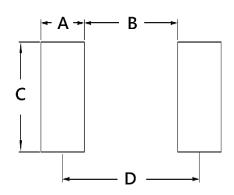




DIM	Unit	(mm)	Unit (inch)		
DIIVI	Min	Max	Min	Max	
Α	3.60	4.00	0.142	0.157	
В	2.30	2.70	0.091	0.106	
С	1.60	1.90	0.063	0.075	
D	0.90	1.10	0.035	0.043	
E	0.10	0.22	0.004	0.009	
F	0.00	0.10	0.000	0.004	
G	0.30	0.60	0.012	0.024	
Н	0.40	0.80	0.016	0.031	
I	4.40	5.00	0.173	0.197	

SUGGESTED PAD LAYOUT

- I -



DIM	Unit (mm)	Unit (inch)
Α	1.40	0.055
В	3.00	0.118
С	2.10	0.082
D	4.40	0.173

MARKING DIAGRAM



P/N = Marking Code ΥW = Date Code F = Factory Code



Taiwan Semiconductor

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Taiwan Semiconductor:

S1JFS MWG S1JFS MXG S1DFSHMWG S1JFSHMXG S1GFS MXG S1KFSHMWG S1KFSHMXG S1MFS MWG S1GFSHMWG S1KFS MWG S1MFS MWG S1GFS MWG S1DFSHMXG S1MFSHMWG S1DFS MWG S1DFS MWG S1DFS MWG S1DFS MWG S1DFS MWG S1DFS MXG S1GFS MXG S1GFS